DRA9143X

Silicon PNP epitaxial planar type

For digital circuits

Complementary to DRC9143X

■ Features

- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

■ Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

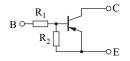
| Parameter | Symbol | Rating | Unit | |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V _{CBO} | -50 | V | |
| Collector-emitter voltage (Base open) | V _{CEO} | -50 | V | |
| Collector current | I_{C} | -100 | mA | |
| Total power dissipation | P _T | 125 | mW | |
| Junction temperature | T_j | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

■ Package

• Code

SSMini3-F3-B

- Pin Name
 - 1: Base
 - 2: Emitter
 - 3: Collector
- Marking Symbol: L6
- Internal Connection



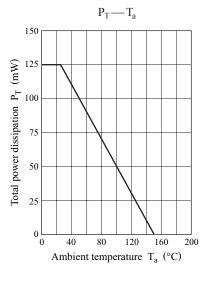
| Resistance | R_1 | 4.7 | kΩ |
|------------|----------------|-----|----|
| value | R ₂ | 10 | kΩ |

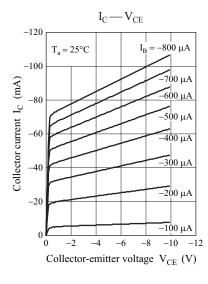
■ Electrical Characteristics $T_a = 25$ °C±3°C

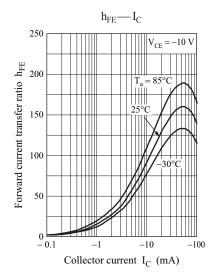
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|--|------|------|-------|------|
| Collector-base voltage (Emitter open) | V _{CBO} | $I_{\rm C} = -10 \mu{\rm A}, I_{\rm E} = 0$ | -50 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_C = -2 \text{ mA}, I_B = 0$ | -50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = -50 \text{ V}, I_E = 0$ | | | -0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = -50 \text{ V}, I_{B} = 0$ | | | -0.5 | μΑ |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = -6 \text{ V}, I_C = 0$ | | | -1.0 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$ | 30 | | | _ |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$ | | | -0.25 | V |
| Input voltage (ON) | V _{I(on)} | $V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$ | -1.7 | | | V |
| Input voltage (OFF) | V _{I(off)} | $V_{CE} = -5 \text{ V}, I_{C} = -100 \mu\text{A}$ | | | -0.6 | V |
| Input resistance | R_1 | | -30% | 4.7 | +30% | kΩ |
| Resistance ratio | R_1/R_2 | | 0.37 | 0.47 | 0.57 | _ |

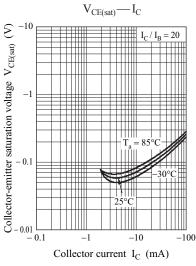
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

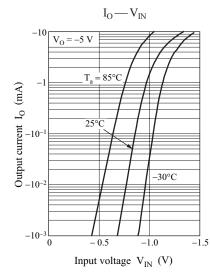
DRA9143X Panasonic

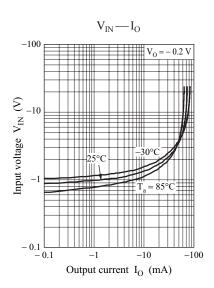








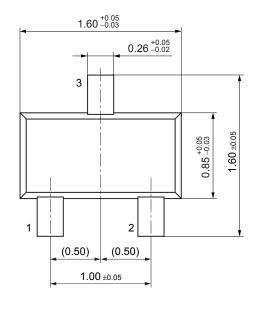


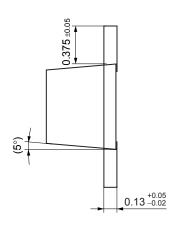


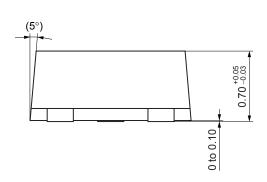
2 ZJH00323BED

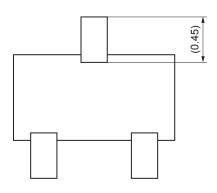
SSMini3-F3-B

Unit: mm









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